NSN 5961-01-097-4736

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-097-4736 **Inclosure Material:** Metal **Overall Diameter:** 1.227 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-94 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 repetitive peak reverse voltage, peak total value and 1100.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 125.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator: Terminal Type And Quantity:** 1 threaded stud and 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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